

# Supplementary Information

## Ultra-low detection limit chemoresistive NO<sub>2</sub> gas sensor using single transferred MoS<sub>2</sub> flake: an advanced nanofabrication

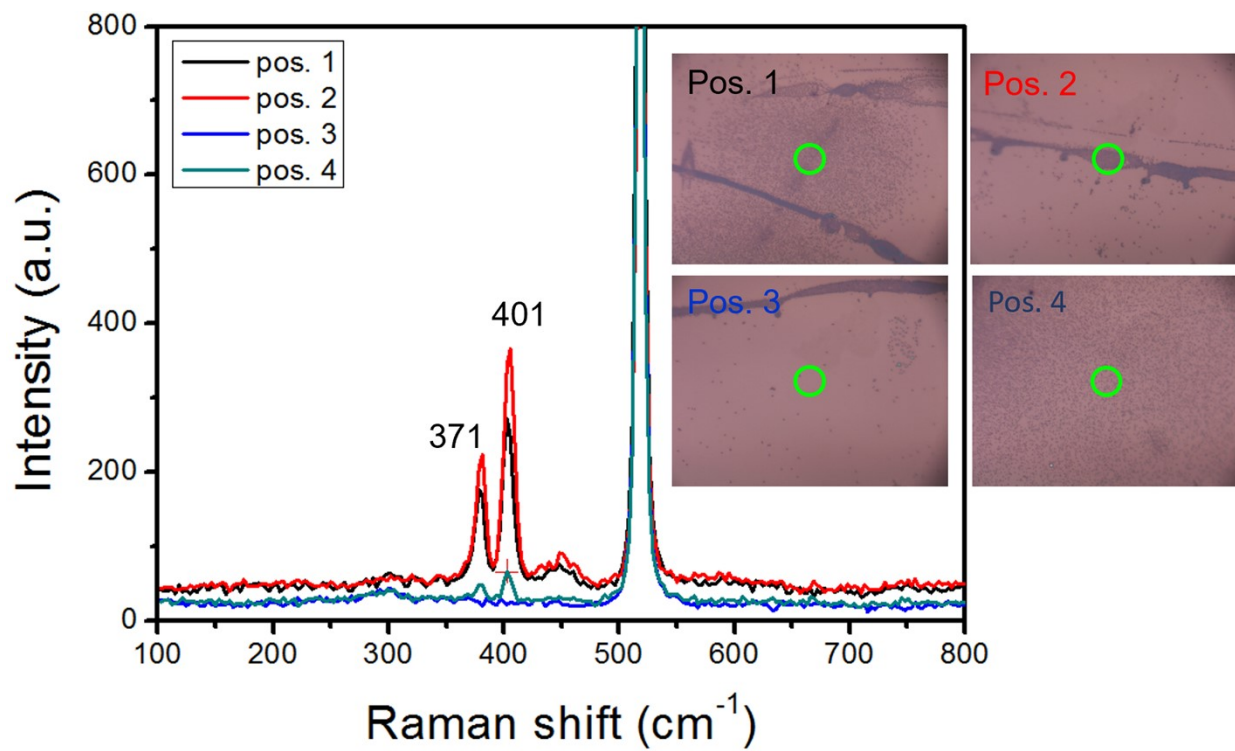
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28 **Figure S1.** Raman spectra of transferred MoS<sub>2</sub> on SiO<sub>2</sub>/Si substrate

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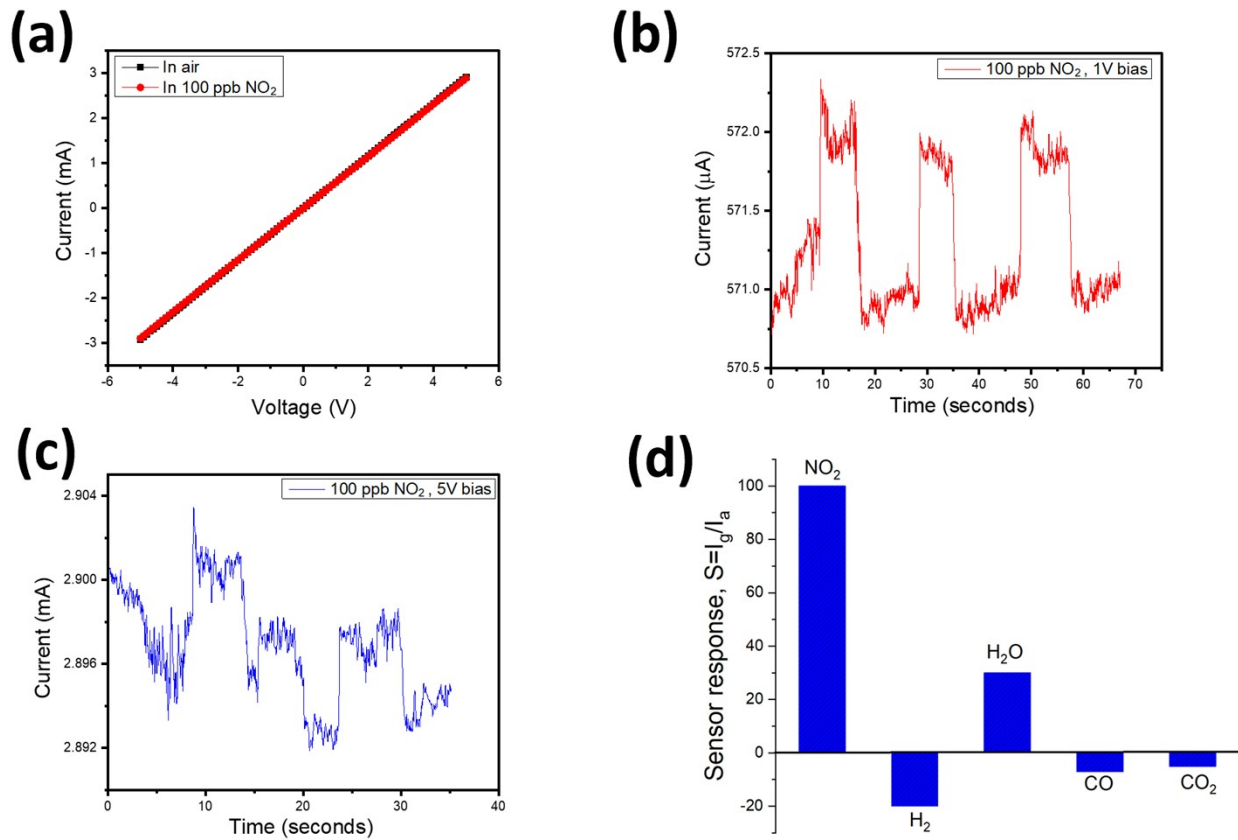
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42 **Figure S2.** (a,b,c) The response of sensor with similar structure fabricated on pure graphene  
 43 (without MoS<sub>2</sub>) for comparison purpose, (d) the selectivity of fabricated sensor of Au-MoS<sub>2</sub>-Au  
 44 (measured at 1000 ppb).

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